Unitized Semiconductor Devices - Page 1 of 1

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Inclosure Material:
Ceramic
Overall Length:
0.786 inches
Component Name And Quantity:
4 transistor
Mounting Method:
Terminal
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
30.0 drain to source voltage all transistor
Current Rating Per Characteristic:
0.32 amperes drain current all transistor
Power Rating Per Characteristic:
3.0 watts total device dissipation all transistor
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Terminal Type And Quantity:
14 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0